

Solid State Broadband High Power Amplifier

2010 - BBS5A7AHM

The BBS5A7AHM (SKU 2010) is suitable for S-Band broadband and band specific high power linear applications. This amplifier utilizes high power GaAsFET devices that provide high gain, wide dynamic range, low distortions and excellent linearity. Exceptional performance and high efficiency are achieved by employing advanced broadband RF matching networks and combining techniques, built in high quality power supply, EMI/RFI filters, machined housings and all qualified components. Empower RF's ISO9001 Quality Assurance Program assures consistent performance and the highest reliability.

- Solid-state linear design
- Instantaneous ultra broadband
- Small and lightweight
- Standard front panel manual gain adjust
- Suitable for CW, AM, and FM (Consult factory for other modulation types)
- 50 ohm input/output impedance
- High reliability and ruggedness

ELECTRICAL SPECIFICATIONS @ $120V_{AC}$, $25^{\circ}C$, 50Ω system

Parameter	Symbol	Min	Тур	Max	Unit
Operating Frequency	BW	2000		4000	MHz
Output Power CW	PSAT	50	60		Watt
Output Power @ 1dB Gain Compression	P _{1dB}	40			Watt
Power Gain @ 1dB Gain Compression	G _{1dB}	46			dB
Input Power for Rated PSAT	PIN		0		dBm
Small Signal Gain Flatness	ΔG			±1.5	dB
Gain Adjustment Range	FGA	25			dB
Input Return Loss	S ₁₁			-10	dB
Noise Figure	NF			10	dB
Third Order Intercept Point 2-Tone @ 37dBm/Tone, 100kHz Spacing	IP3		+56		dBm
Harmonics @ P _{OUT} = 40W	H		-20		dBc
Spurious Signals	Spur		-70	-60	dBc
Operating Voltage (single phase)	V _{AC}	100		240	Volt
Power Consumption @ P _{OUT} = 50W CW	PD		400	500	Watt

MECHANICAL SPECIFICATIONS

Parameter	Value	Units	Limits
Dimension	19 x 5.25 x 22	Inch	-
Weight	47	lb.	-
RF Connectors Input / Output	Type-N, Female	-	-
Cooling	Built-in forced air cooling system	-	-

ENVIRONMENTAL CHARACTERISTICS (Design to Meet)

Parameter	Symbol	Min	Тур	Max	Unit
Operating Temperature	T _c	0		+50	°C
Non-operating Temperature	T _{STG}	-40		+85	°C
Relative Humidity (non-condensing)	RH			95	%
Altitude (MIL-STD-810F Method 500.4)	ALT			30,000	Feet
Vibration / Shock MIL-STD-810F - Method 514.5/516.5 – Proc I	VI / SH		Airborne		

LIMITS

Input RF drive level without damage	+10 dBm	Max
Load VSWR @ P _{OUT} = 40W	 ∞ @ all load phase & amplitude for duration of 1 minute 3:1 @ all load phase & amplitude continuous 	-
Thermal Overload	85°C shutdown	Max

2000 - 4000 MHz / 50 Watts



Shown with option package 10



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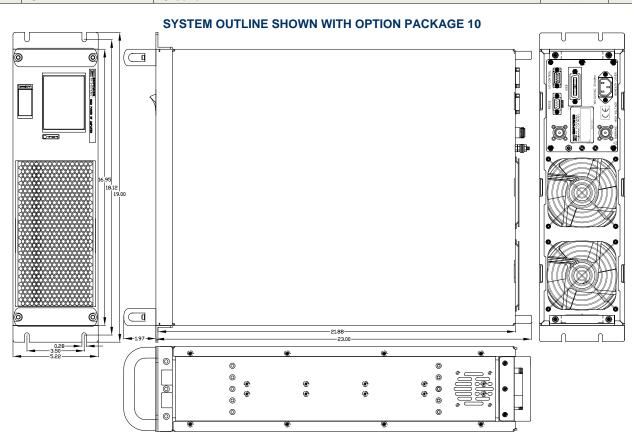
AVAILABLE OPTIONS (for complete option list refer to www.empowerrf.com)

Option	Number	Description	Price
FGA	061	Front panel 10 turns manual gain adjustment.	Standard
LCD	062	Touchscreen Digital Display, including Fwd/Rev Power indication (dBm or Watt scale), Gain Adjustment, ALC Fast/Slow, On/Off, Standby mode, Fault indication, Rear panel GPIB / IEEE-488.2 and half duplex RS-232 or Full Duplex RS-422 remote interface. Note: Output Power is lowered by 0.5 - 0.75 dB with this option.	Call
FCN	051	Front Panel Type-N female	N/C
RCN	052	Rear Panel Type-N female	N/C

Available Options Packages: 07, 08, 09, 10

I/O INTERFACE CONNECTOR – D-Sub 9-Pin, Female

Pin # Description		Specifications		Options	
		Specifications	FGA	LCD	
1	Forward Test Point	Analog Voltage 0-5V _{DC} relative to Forward Power Level		\checkmark	
2	Reverse Test Point	Analog Voltage 0-5V _{DC} relative to Reverse Power Level			
3	5V Test Point	Output +5.0V _{DC} ±0.2V	\checkmark	\checkmark	
4	VVA Test Point	VVA Gain Control +5.6V _{DC} ±0.2V	\checkmark		
5	EXT Shutdown	Amplifier Disable: TTL Logic High (5V)	2	al	
5	5 EXT Shuldown	(Internally Pulled-Low)	v	v	
6	12V Test Point	Output +12.0V _{DC} \pm 0.5V	\checkmark	\checkmark	
7	P/S Test Point	Power Supply Output voltage: +12.0-15.0V _{DC}	\checkmark	\checkmark	
8	GND	Ground	\checkmark	\checkmark	
9	GND	Ground	\checkmark	\checkmark	





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